## Amendments to the Claims:

This listing of claims will replace all prior version, and listings, of claims in the application:

## **Listing of Claims:**

To:

 (Currently amended) A method of fabricating a liquid crystal display device, comprising the steps of: providing a substrate;

forming a plurality of transversely extending gate lines on the substrate;

forming a first insulating layer on the substrate and the gate lines;

performing a photolithography procedure using a photomask to form a plurality of longitudinally extending data lines and a plurality of metallic light shield layers on part of the first insulating layer without contacting source/drain electrodes, wherein the metallic light shield layers are located on both sides of the data line;

forming a second insulating layer on the metallic light shield layers and the data lines; and forming one or more conductive plugs that penetrate the second insulating layer; and forming one or more transparent conductive layers on part of the second insulating layer, so that the metallic light shield layers and the one or more transparent conductive layers are electrically connected.

- 2. (Canceled).
- 3. (Currently amended) The method according to claim 1, wherein the substrate is a glass substrate comprised of glass.

- 5. (Currently amended) The method according to claim 1, wherein the second insulating layer is a comprises a silicon oxide (SiOx) layer.
- 6. (Currently amended) The method according to claim 1, wherein the metallic light shield layers and the data lines comprise at least one selected from the group consisting of Al, Mo, or, an alloy of Al and Mo.
- 7. (Currently amended) The method according to claim 1, wherein the transparent conductive layers are comprise one selected from the group of ITO (indium tin oxide) [[or]] and IZO (indium zinc oxide) layers.
- 8. (Currently amended) The method according to claim 21, wherein the metallic light shield layers and the transparent conductive layers are equipotential.
- 9-12. (Canceled)
- 13. (New) A liquid crystal display device, comprising:
  - a substrate;
  - a plurality of transversely extending gate lines on the substrate;
  - a first insulating layer on the substrate and the gate lines;

a plurality of longitudinally extending data lines and a plurality of metallic light shield layers on part of the first insulating layer without contacting source/drain electrodes, wherein the metallic light shield layers are located on both sides of the data line;

a second insulating layer on the metallic light shield layers and the data lines;

one or more conductive plugs penetrating the second insulating layer, and

one or more transparent conductive layers on part of the second insulating layer, wherein the metallic light shield layers and the one or more transparent conductive layers are electrically connected.

- 14. (New) The device according to claim 13, wherein the substrate is comprised of glass.
- 15. (New) The device according to claim 13, wherein the first insulating layer comprises a silicon oxide (SiOx) layer.
- 16. (New) The device according to claim 13, wherein the second insulating layer comprises a silicon oxide (SiOx) layer.
- 17. (New) The device according to claim 13, wherein the metallic light shield layers and the data lines comprise Al, Mo, or an alloy of Al and Mo.
- 18. (New) The device according to claim 13, wherein the transparent conductive layers comprise ITO (indium tin oxide) or IZO (indium zinc oxide) layers.

19. (New) The device according to claim 13, wherein the metallic light shield layers and the transparent conductive layers are equipotential.